

ELECTRICAL SPECIFICATIONS (T_{case} = 25°C)

STATIC

Symbol	Test Conditions	Value			Unit
		Min.	Typ.	Max.	
BV_{CBO}	I_C = 50 mA I_E = 0 mA	65	---	---	V
BV_{EBO}	I_E = 15 mA I_C = 0 mA	3.5	---	---	V
BV_{CER}	I_C = 50 mA R_{BE} = 10Ω	65	---	---	V
I_{CES}	V_{BE} = 50 V V_{CE} = 0 V	---	---	30	mA
h_{FE}	V_{CE} = 5 V I_C = 5 A	10	---	---	---

DYNAMIC

Symbol	Test Conditions	Value			Unit
		Min.	Typ.	Max.	
P_{OUT}	f = 1090 MHz P_{IN} = 63W V_{CC} = 50V	400	---	---	W
η_C	f = 1090 MHz P_{IN} = 63W V_{CC} = 50V	45	---	---	%
G_p	f = 1090 MHz P_{IN} = 63W V_{CC} = 50V	8.0	---	---	dB

Conditions: Pulse Width = 32μS Duty Cycle = 2%

IMPEDANCE DATA

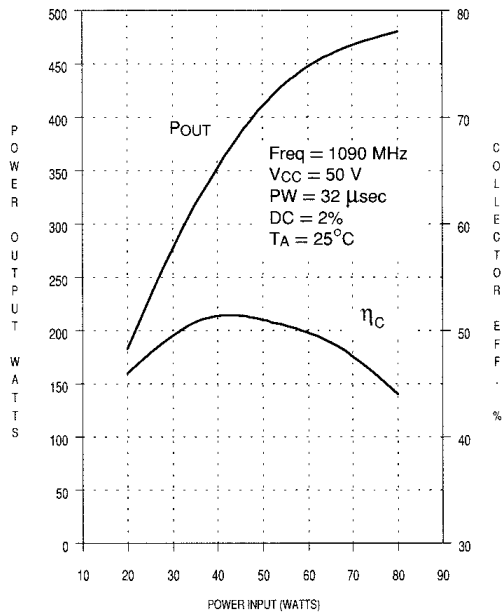
FREQ	Z _{IN} (Ω)	Z _{CL} (Ω)
1025 MHz	2.4 + j 3.2	1.4 – j 2.2
1090 MHz	3.8 + j 2.5	1.6 – j 1.6
1150 MHz	2.3 + j 1.3	1.2 – j 1.1

P_{IN} = 63 W

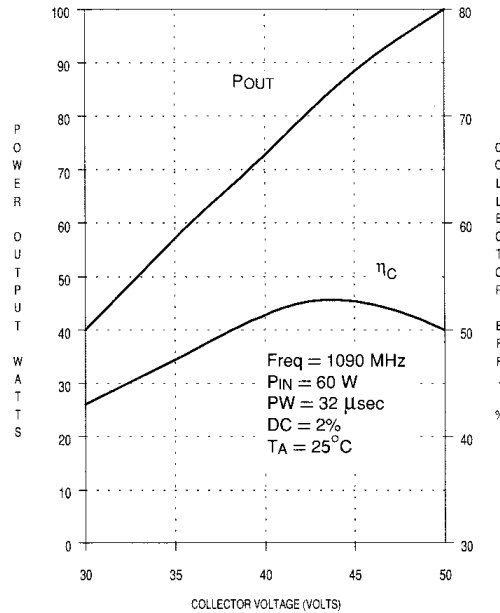
V_{CC} = 50 V

TYPICAL PERFORMANCE

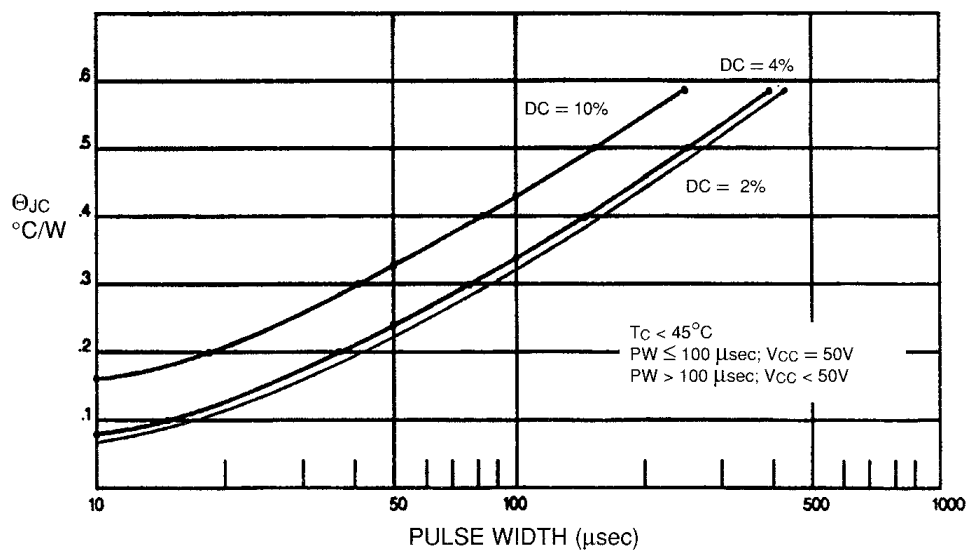
**TYPICAL NARROWBAND
POWER AMPLIFIER**



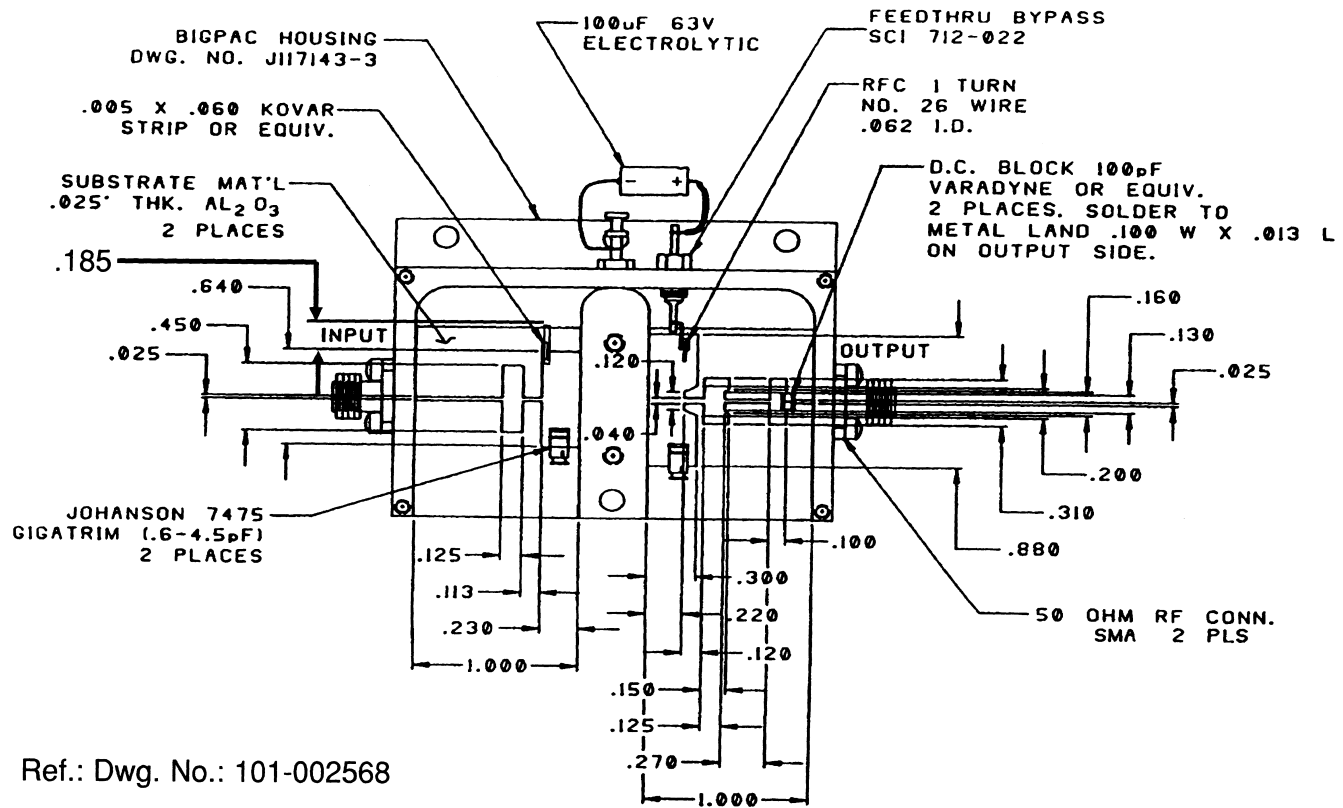
**TYPICAL RELATIVE OUTPUT
POWER & COLLECTOR EFFICIENCY
vs COLLECTOR VOLTAGE**



MAXIMUM THERMAL RESISTANCE vs PULSE WIDTH & DUTY CYCLE



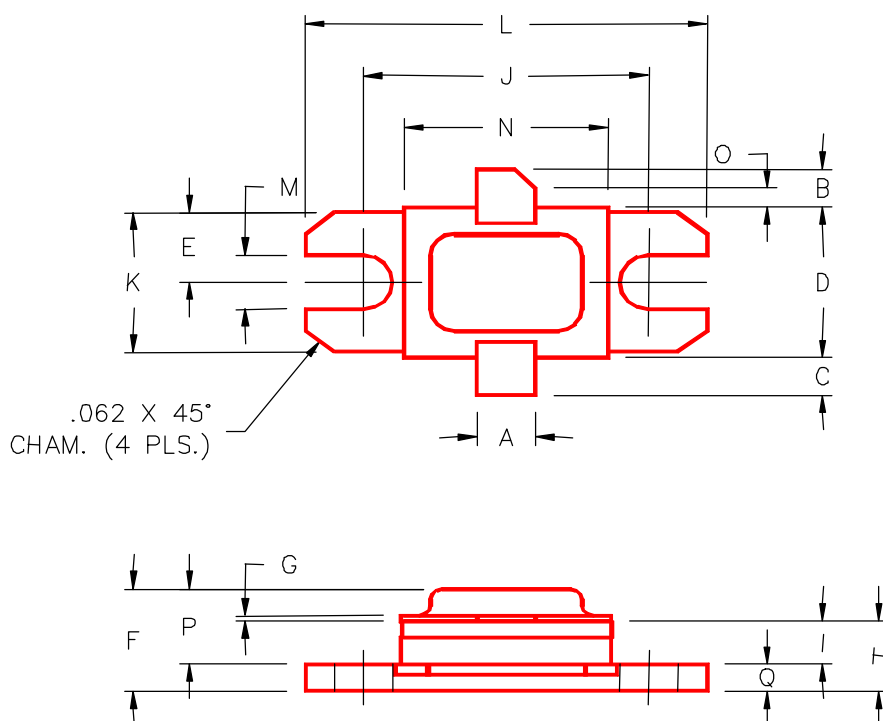
TEST CIRCUIT



Ref.: Dwg. No.: 101-002568

PACKAGE MECHANICAL DATA

PACKAGE STYLE M216



	MINIMUM INCHES/MM	MAXIMUM INCHES/MM		MINIMUM INCHES/MM	MAXIMUM INCHES/MM
A	.140/3,56		J	.700/17,78	
B	.110/2,80		K	.386/9,80	
C	.110/2,80		L	.900/22,86	
D	.395/10,03	.407/10,34	M	.120/3,05	
E	.193/4,90		N	.500/12,70	
F		.230/5,84	O	.050/1,27	
G	.003/0,08	.006/0,15	P		.170/4,32
H	.118/3,00	.131/3,33	Q	.062/1,58	
I	.063/1,60				